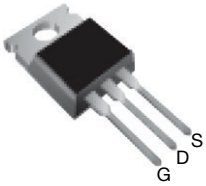
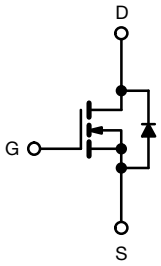
Power MOSFET

TO-220AB





N-Channel MOSFET

FEATURES

- Extremely low $R_{DS(on)}$
- Compact plastic package
- Fast switching
- Low drive current
- Ease of paralleling
- Excellent temperature stability
- Parts per million quality
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Available

RoHS* Available

Note

* This datasheet provides information about parts that are RoHS-compliant and / or parts that are non RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details

PRODUCT SUMMARY		
V_{DS} (V)	50	
$R_{DS(on)}$ (Ω)	V_{GS} = 10 V	0.10
Q_g (Max.) (nC)	17	
Q_{gs} (nC)	9.0	
Q_{gd} (nC)	3.0	
Configuration	Single	

DESCRIPTION

The technology has expanded its product base to serve the low voltage, very low $R_{DS(on)}$ MOSFET transistor requirements. Vishay's highly efficient geometry and unique processing have been combined to create the lowest on resistance per device performance. In addition to this feature all have documented reliability and parts per million quality!

The transistor also offer all of the well established advantages of MOSFETs such as voltage control, very fast switching, ease of paralleling, and temperature stability of the electrical parameters.

They are well suited for applications such as switching power supplies, motor controls, inverters, choppers, audio amplifiers, high energy pulse circuits, and in systems that are operated from low voltage batteries, such as automotive, portable equipment, etc.

ORDERING INFORMATION	
Package	TO-220AB
Lead (Pb)-free	IRFZ20PbF
Lead (Pb)-free and halogen-free	IRFZ20PbF-BE3

ABSOLUTE MAXIMUM RATINGS

PARAMETER			SYMBOL	LIMIT	UNIT
Drain-source voltage [a]			V_{DS}	50	V
Gate-source voltage [a]			V_{GS}	± 20	
Continuous drain current	V_{GS} at 10 V	T_C = 25 °C	I_D	15	A
		T_C = 100 °C		10	
Pulsed drain current [b]			I_{DM}	60	
Single pulse avalanche energy [c]			E_{AS}	5	mJ
Linear derating factor (see fig. 16)				0.32	W/°C
Maximum power dissipation (see fig. 16)	T_C = 25 °C		P_D	40	W
Operating junction and storage temperature range			T_J, T_{stg}	-55 to +150	°C
Soldering recommendations (peak temperature)	For 10 s			300 (0.063" (1.6 mm) from case	

Notes

a. T_J = 25 °C to 150 °C

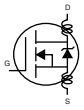
b. Repeditive rating: Pulse width limited by max. junction temperature. See transient temperature impedance curve (see fig. 11)

c. Starting T_J = 25 °C, L = 0.07 mH, R_g = 25 Ω, I_{AS} = 12 A

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THERMAL RESISTANCE RATINGS				
PARAMETER	**SYMBOL**	**TYP.**	**MAX.**	**UNIT**
Typical socket mount, junction-to-ambient	R_{thJA}	-	80	°C/W
Case-to-sink, mounting surface flat, smooth, and greased	R_{thCS}	1.0	-	
Junction-to-case	R_{thJC}	-	3.12	

SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA		50	-	-	V
V_{DS} temperature coefficient	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA		2.0	-	4.0	V
Gate-source threshold voltage	I_{GSS}	V_{GS} = ± 20 V		-	-	± 500	nA
Gate-source leakage	I_{DSS}	V_{DS} > Max. Rating, V_{GS} = 0 V		-	-	250	µA
Zero gate voltage drain current		V_{DS} = Max. Rating x 0.8, V_{GS} = 0 V, T_C = 125 °C		-	-	1000	
	$I_{D(on)}$	V_{GS} = 10 V	V_{DS} > $I_{D(on)}$ x $R_{DS(on)}$ max.	-	-	15	A
Drain-source on-state resistance [b]	$R_{DS(on)}$	V_{GS} = 10 V	I_D = 10 A	-	0.080	0.10	Ω
Forward transconductance [b]	g_{fs}	V_{DS} > $I_{D(on)}$ x $R_{DS(on)}$ max., I_D = 9.0 A		5.0	6.0	-	S
Dynamic							
Input capacitance	C_{iss}	V_{GS} = 0 V, V_{DS} = 25 V, f = 1.0 MHz, see fig. 11		-	560	860	pF
Output capacitance	C_{oss}			-	250	350	
Reverse transfer capacitance	C_{rss}			-	60	100	
Total gate charge	Q_g	V_{GS} = 10 V	I_D = 20 A, V_{DS} = 0.8 max. rating, see fig. 18 for test circuit (Gate charge is essentially independent of operating temperature)	-	12	17	nC
Gate-source charge	Q_{gs}			-	9.0	-	
Gate-drain charge	Q_{gd}			-	3.0	-	
Turn-on delay time	$t_{d(on)}$	V_{DD} = 25 V, I_D = 9.0 A, Z_0 = 50 Ω, see fig. 5[b]		-	15	30	ns
Rise time	t_r			-	45	90	
Turn-off delay time	$t_{d(off)}$			-	20	40	
Fall time	t_f			-	15	30	
Internal drain inductance	L_D	Modified MOSFET symbol showing the internal device inductances 		-	3.5	-	nH
Internal source inductance	L_S			-	4.5	-	
Drain-Source Body Diode Characteristics							
Continuous source-drain diode current	I_S	MOSFET symbol showing the integral reverse p - n junction rectifier 		-	-	15	A
Pulsed diode forward current [a]	I_{SM}			-	-	60	
Body diode voltage [b]	V_{SD}	T_C = 25 °C, I_S = 15 A, V_{GS} = 0 V		-	-	1.5	V
Body diode reverse recovery time	t_{rr}	T_J = 150 °C, I_F = 15 A, dI_F/dt = 100 A/µs		-	100	-	ns
Body diode reverse recovery charge	Q_{rr}			-	0.4	-	µC
Forward turn-on time	t_{on}	Intrinsic turn-on time is negligible (turn-on is dominated by L_S and L_D)					

Notes

a. Repeditive rating: Pulse width limited by max. junction temperature. See transient temperature impedance curve (see fig. 5)

b. Pulse test: Pulse width ≤ 300 µs; duty cycle ≤ 2 %

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

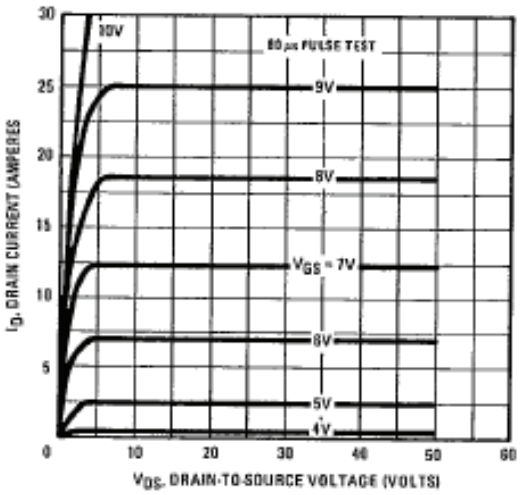


Fig. 1 - Typical Output Characteristics

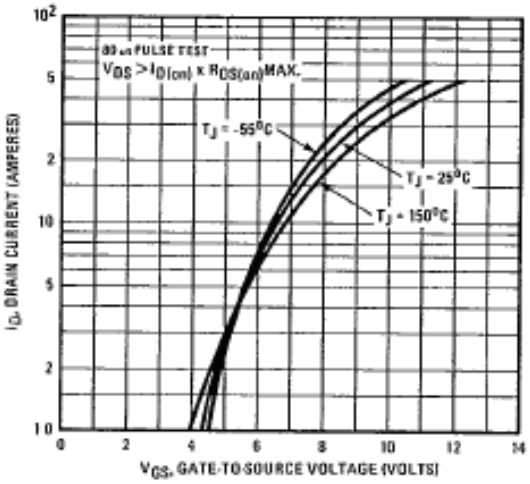


Fig. 1 - Typical Transfer Characteristics

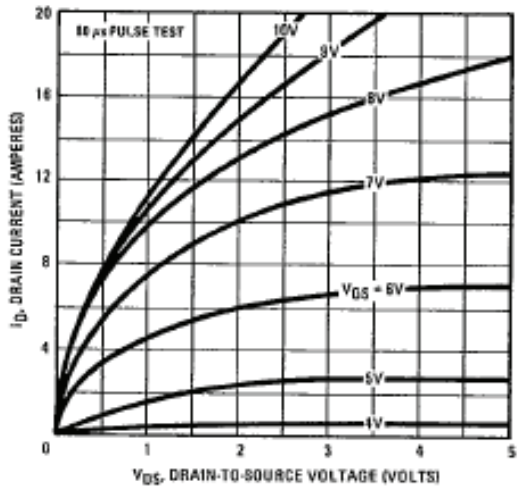


Fig. 2 - Typical Saturation Characteristics

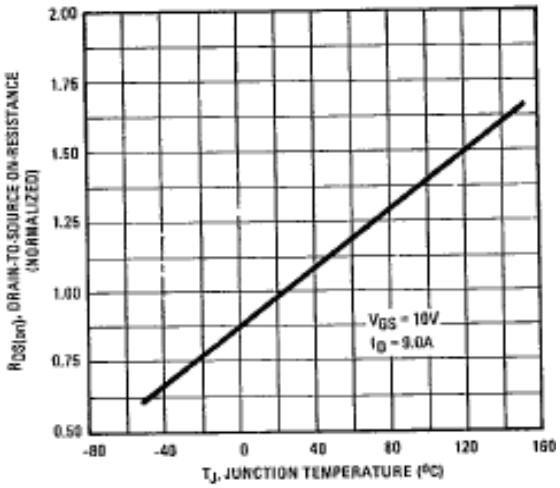


Fig. 2 - Normalized On-Resistance vs. Temperature

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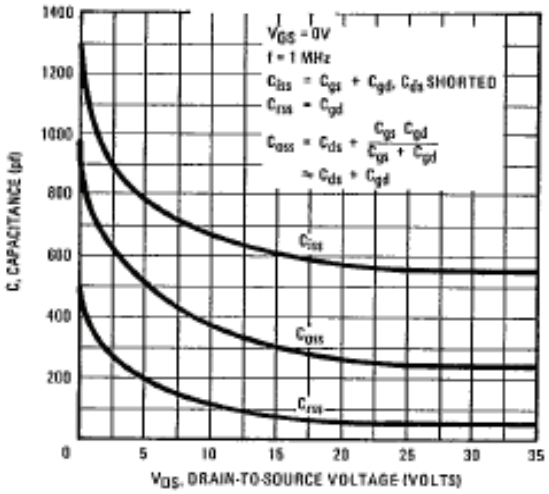


Fig. 3 - Typical Capacitance vs. Drain-to-Source Voltage

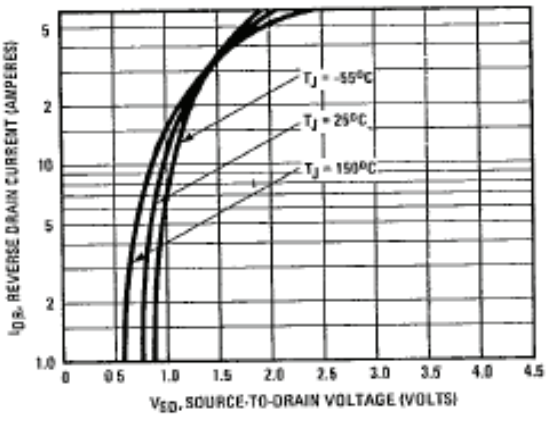


Fig. 5 - Typical Source-Drain Diode Forward Voltage

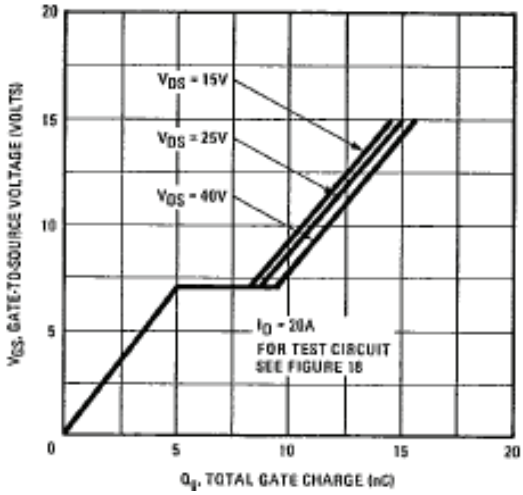


Fig. 4 - Typical Gate Charge vs. Gate-to-Source Voltage

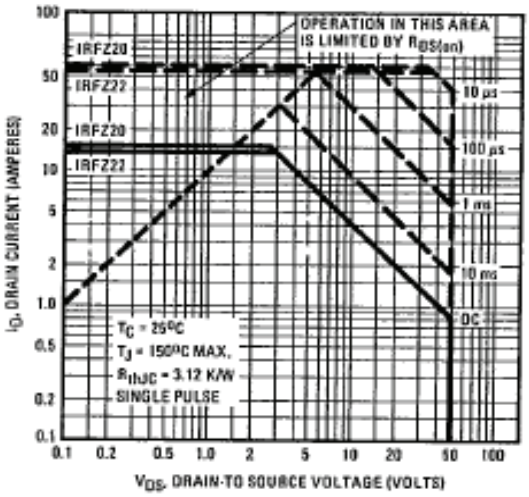


Fig. 6 - Maximum Safe Operating Area

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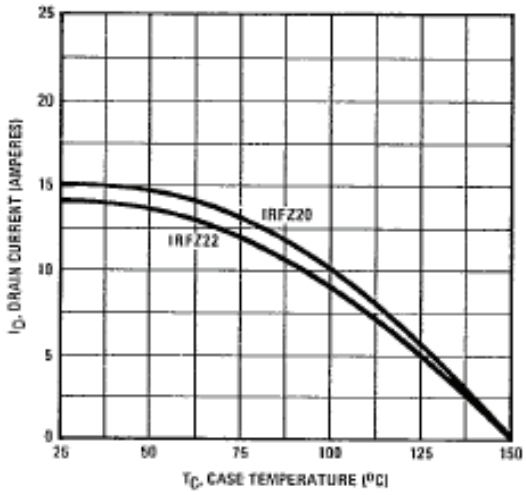


Fig. 7 - Maximum Drain Current vs. Case Temperature

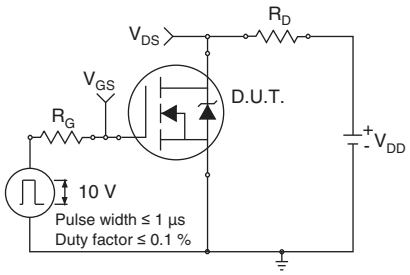


Fig. 10a - Switching Time Test Circuit

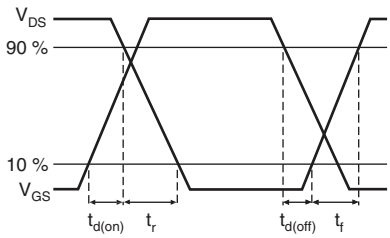


Fig. 10b - Switching Time Waveforms

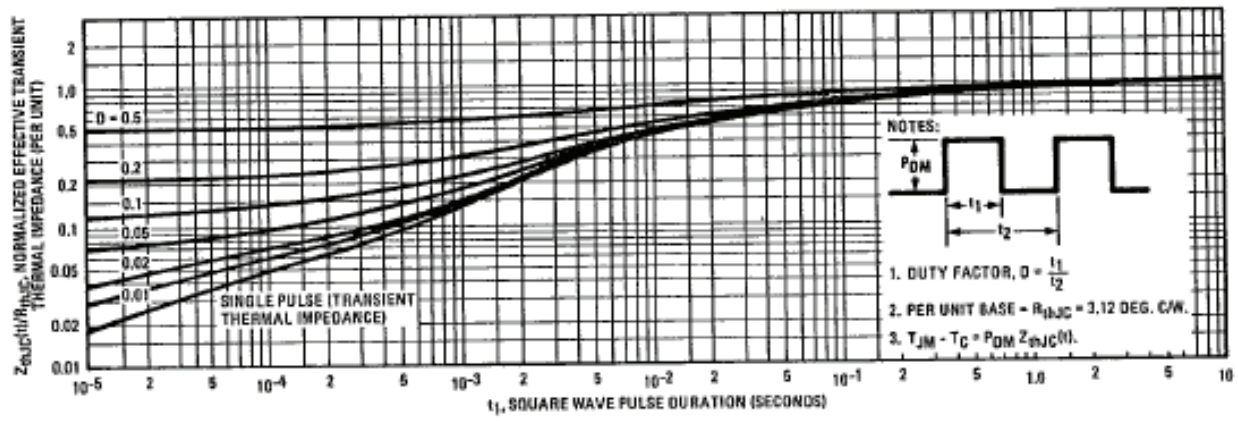


Fig. 11 - Maximum Effective Transient Thermal Impedance, Junction-to-Case vs. Pulse Duration

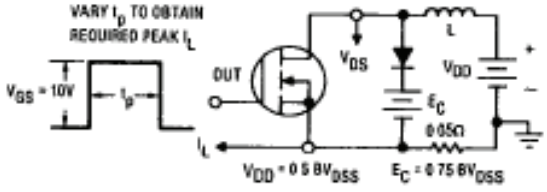


Fig. 12a - Clamped Inductive Test Circuit

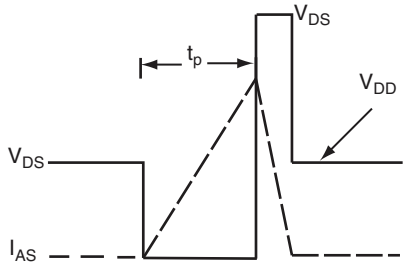


Fig. 12b - Unclamped Inductive Waveforms

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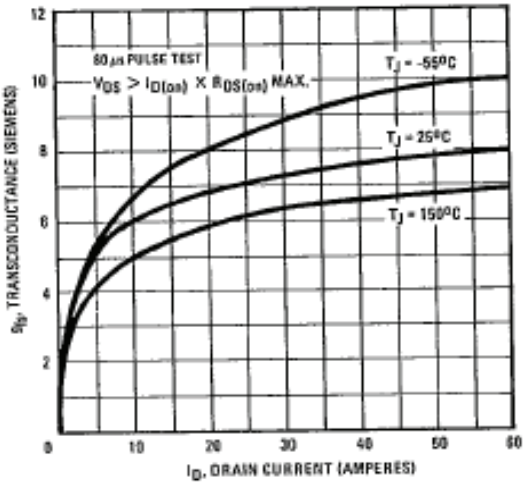


Fig. 13 - Typical Transconductance vs. Drain Current

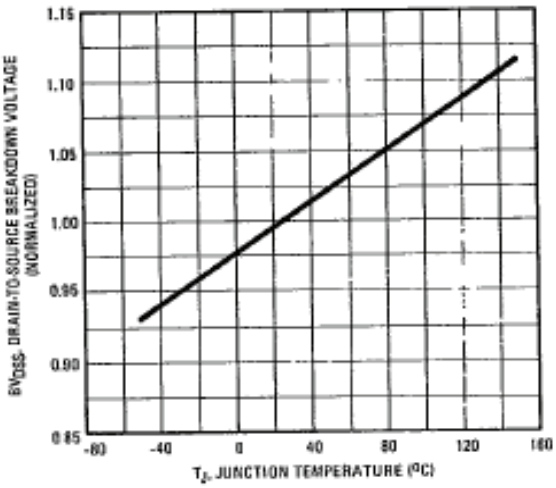


Fig. 14 - Breakdown Voltage vs. Temperature

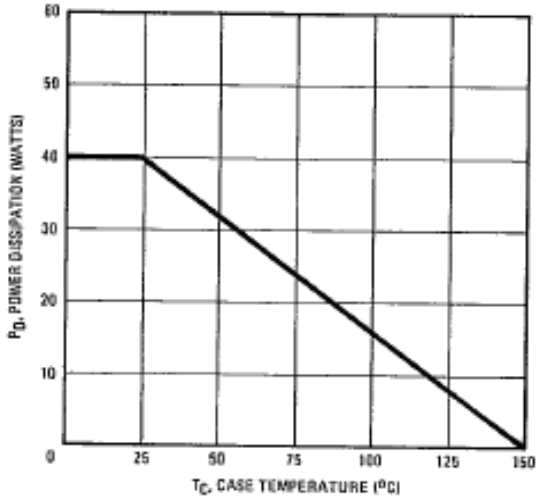


Fig. 16 - Power vs. Temperature Derating Curve

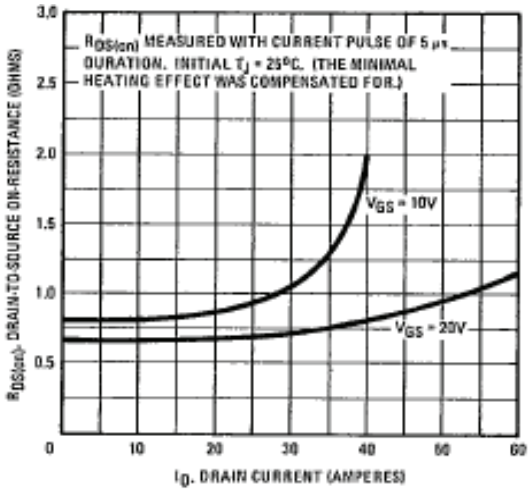


Fig. 15 - Typical On-Resistance vs. Drain Current

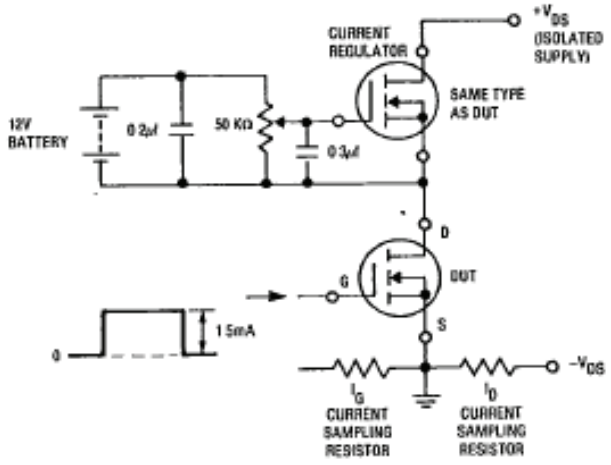
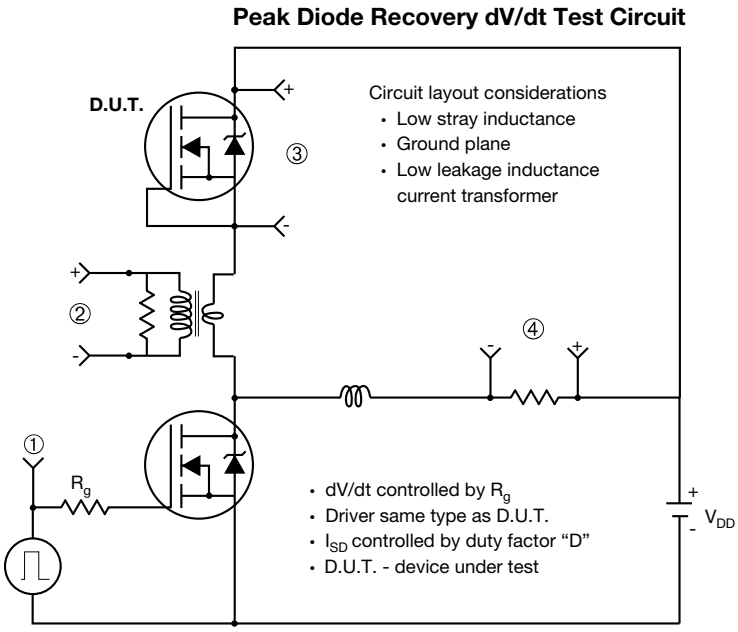
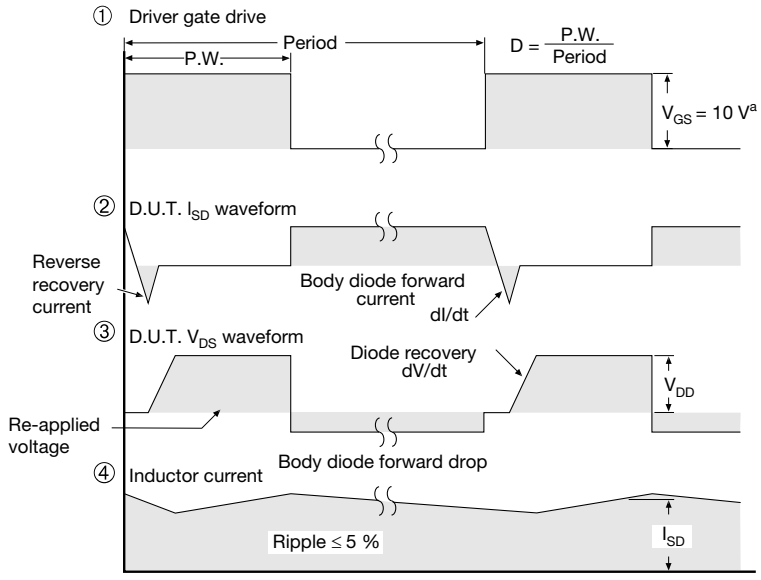


Fig. 17 - Gate Charge Test Circuit

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Note

a. V_{GS} = 5 V for logic level devices

Fig. 14 - For N-Channel

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